

SemiNex delivers the highest available CW power at infrared wavelengths. SemiNex will optimize the design of its laser chips to meet customers' optical and electrical performance specifications. Diodes are mounted and tested to meet custom applications. Typical results and packaging options are shown below. Contact SemiNex for additional details or to discuss your application.

Key Features

- High output power
- · High dynamic power range
- High efficiency
- · Custom packaging

Applications

- Medical laser equipment
- LIDAR
- Free Space Optical Communication
- DPSS pump lasers
- Military / Aerospace



0.05

ohm

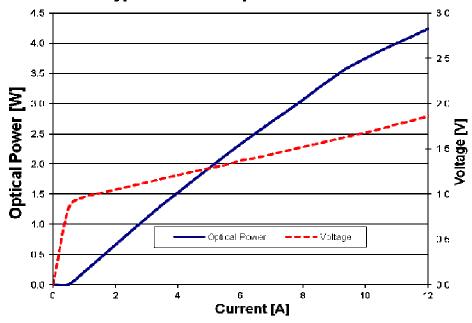
High Power Multi-Mode SemiNex Lasers 3.8 Watts of Continuous Operation Power 1350, 1470, 1532, or 1550 nm Wavelength 4-Pin Fiber-Coupled

	Symbol	Typical	Units
Optical			
Output power (CW)	P_{o}	3.8	watts
Center Wavelength Range	λ_{c}	1350, 1470, 1532, 1550	nm
Emitter Width	W	95	μm
Emitter Height	Н	1	μm
Spectral Width	Δλ	10	nm 3dB
Slope Efficiency	η_{o}	0.4	W/A
Optical Fiber Core Diameter		105	μm
Optical Fiber NA		0.22	
Wavelength Temp. Coeff.	λ_{coef}	0.7	nm/C
Electrical			
Power conversion Efficiency	η	0.2	
Threshold Current	I_{th}	0.45	Α
Operating Current	I_{op}	10	Α
Operating Voltage	V_{op}	1.8	V

Typical CW LIV Optical Power Chart

 R_s

Series Resistance

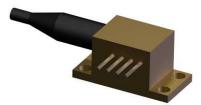


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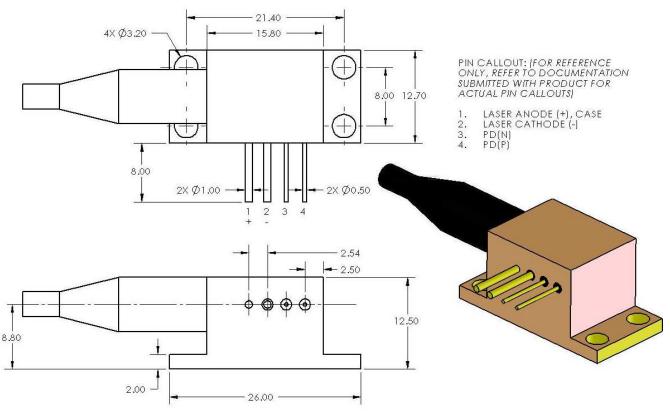






	Symbol	4PN-104	4PN-106	4PN-108	4PN-109	Units
Optical						
Output power (CW)	P _o	3.8	4.0	3.3	3.3	watts
Center Wavelength	λ_{c}	1470	1470	1532	1550	nm
Emitter Width	W	95	95	95	95	μm
Emitter Height	Н	1	1	1	1	μm
Spectral Width	Δλ	10	10	10	10	nm 3dB
Slope Efficiency	$\eta_{ m o}$	0.4	0.4	0.4	0.4	W/A
Optical Fiber Core Diameter		105	105	105	105	μm
Optical Fiber NA		0.22	0.15	0.22	0.22	

Electrical						
Power conversion Efficiency	η	0.2	0.2	0.2	0.2	
Threshold Current	\mathbf{I}_{th}	0.45	0.45	0.45	0.45	Α
Operating Current	I_{op}	10	12	10	10	Α
Operating Voltage	V_{op}	1.75	1.75	1.75	1.75	V
Series Resistance	R_s	0.05	0.07	0.05	0.05	ohm
Lead Soldering Temperature	C	250	250	250	250	С



NOTE: Dimensions are in mm

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